A BAW Resonator Based RF Subsampling Band Pass ΣΔ Modulator

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Abstract—A new design technique of RF subsampling continuous time bandpass sigma delta modulator is presented in this paper. The modulator employs a Bulk Acoustic Wave (BAW) resonator. A robust method to eliminate the anti-resonance frequency of the resonator is detailed. Combining subsampling process with BAW technology offers a promising solution to reduce sampling frequency and power consumption of the ΣΔ modulator with high quality-factor. A fourth-order continuous time subsampling bandpass ΣΔ modulator is studied as an example. The Signal Transfer Function and Noise Transfer Function are compared in this context. Besides, the effects of employing BAW resonator on the output SNR of the modulator is studied. Simulation results show that using an input RF signal of 1.56 GHz, the SNR measured with and without anti-resonance cancellation are equal, respectively, to 52 dB and 36 dB when subsampled the signal with 902.85 MHz.

Index Terms—BAW resonator, RF Subsampling, bandPass Sigma Delta modulator.

I. INTRODUCTION

Continuous time bandpass sigma delta modulator is seen as a promising candidate for fulfill RF Analog to Digital Converter (ADC) with high speed, high resolution and low power consumption in the context of software radio receivers [1]. RF down-conversion based ΣΔ modulator could be performed by subsampling process in order to reduce sampling frequency. At high frequencies, Continuous-Time (CT) bandpass loop filter of the ΣΔ modulator is usually based on integrated LC resonators [2]. However, the low quality factor Q of the CT resonators can limit the performance of the modulator, particularly for narrowband applications [2]. A Q-enhancement technique can be employed in order resolve this problem [3]. Nevertheless, non linearity and power consumption of the modulator will be increased [4], [5]. On the other hand, it is known that electro-mechanical resonator such as MEMS (Micro Electro Mechanical System), SAW (Surface Acoustice Wave) and BAW (Bulk Acoustic Bave) have a high Q-factor [6]. Thus, they can surmount the limitation of the classical resonators based on integrated LC resonators in CT bandpass ΣΔ modulators. MEMS and SAW resonator present high Q-factor but compatibility issues with CMOS technology and high insertion loss for some configurations will limit its performances. Contrary to MEM and SAW resonators, BAW technology have a lower insertion loss, better selectivity and can be directly integrated above IC[7]. It can offer more opportunities to realize a RF reconfigurable filters for multi-standard receivers. In the present work, we propose to using BAW resonator in order to design a CT-bandpass loop filter for the subsampling ΣΔ modulator.

This paper is organized as follows: Section II reviews BAW resonator characteristics. The proposed subsampling modulator based BAW resonator is described in Section III. A design example and performances analysis of the proposed modulator are studied in this section. Some conclusions are depicted in Section IV.

II. BAW RESONATOR: STRUCTURE AND CHARACTERISTICS

A. Basis Architecture

Two structures are used to build a BAW resonator: FBAR (Film Bulk Acoustic Resonator) and SMR (Solidly Mounted Resonator). A FBAR resonator is a think piezoelectric layers comprised between two electrodes and the acoustic isolation is effected by air gaps. The SMR structure is identical to the first but the isolation is achieved using Bragg reflector. An example of a BAW-SMR resonator structure is shown in Fig. 1. The resonator is composed of alternative layers of low and high acoustic impedance, respectively. The number of layers depends on the acoustic impedance ratio between the straight layers[8].

B. Butterworth Van Dyke Model

The BAW resonator can be studied by using compact electrical model. As described in Fig. 2, the electrical circuit known as “Butterworth Van Dyke Model” can model the BAW resonator. \( L_m \) and \( C_m \) designed the motional behavior of piezoelectric resonator. \( R_m \) is the mechanical losses in the resonator. \( C_p \) is the electrostatic capacitor.

Fig. 1. BAW-SMR resonator

Fig. 2. BVD Model of BAW Resonator
The transfer function of the BVD model of the BAW resonator is given by [6]:

\[ H(s) = \frac{1 + \frac{s}{Q_p w_p} + \frac{s^2}{w_p^2}}{1 + \frac{s}{Q_s w_s} + \frac{s^2}{w_s^2}} \]  

(1)

where:

\[ \omega_s = \frac{1}{\sqrt{L_m C_m}} \]
\[ \omega_p = \omega_s \sqrt{1 + \frac{C_m}{C_p}} \]

(2)

Here, \( \omega_s \) and \( \omega_p \) designed, respectively, the anti-resonance and resonance pulsations. \( Q_s \) and \( Q_p \) are, respectively, the anti-resonant and resonant quality factors. An example of the frequency response of the transfer function response of the BAW-SMR resonator is shown in Fig. 3. The resonant frequency is choosen to \( f_p = 1.58 \) GHz and the anti-resonant frequency is equal to \( f_s = 1.42 \) GHz. Where \( L_m = 20.6 \) nH, \( C_m = 0.61 \) pH, \( R_m = 0.26 \) Ω and \( C_p = 2.54 \) pH. In this example the quality factor \( Q_s \) and \( Q_p \) are equal respectively to 707 and 635. It is clear that an anti-resonant notch is produced.

Then, the modified transfer function of the BAW resonator can be written as [6]:

\[ H_{cancel}(s) = H(s) - \frac{1}{sC_c} \]  

(3)

Using equation (1), we get:

\[ H_{cancel}(s) = \frac{s(C_m / C_p^2)}{s^2 + \left(\frac{\omega_p}{Q_p}\right)s + \omega_p^2} \]  

(4)

As shown in Fig. 5, if the value of \( C_c \) is equal to \( C_p \), the effect of \( C_s \) will be completely canceled. Consequently, the anti-resonance component is canceled and the equation (4) is similar to the transfer function of a LC resonator with a quality factor \( Q_p \) equal to 635. Finally, a BAW compensated resonator with high quality factor has been obtained. It can be used as a continuous time loop filter for bandpass \( \Sigma \Delta \) modulator.

**III. Subsampling Continuous Bandpass \( \Sigma \Delta \) Modulator Based BAW Resonator**

The As detailed in [9], a subsampling continuous bandpass \( \Sigma \Delta \) modulator is the best candidate to downconvert a RF bandpass signal with lower sampling frequency and lower power consumption. In this section, a BAW resonator based CT-bandpass loop filter is used in order to design a fourth order subsampling \( \Sigma \Delta \) modulator.

**A. The Proposed \( \Sigma \Delta \) Modulator**

An example of a subsampling bandpass CT-\( \Sigma \Delta \) Modulator with BAW resonator is shown in Fig. 6. The loop filter of the CT proposed modulator is based on BAW resonator. The problem of anti-resonance is cancelled by adding negative capacitance circuit as detailed in the previous section. A
Sample and Hold (S/H) block is used in order to subsampling the signal at the output of the resonator with a sampling frequency $F_s$. As detailed in [9], the relation between $F_s$ and the center frequency $f_p$ is given by:

$$F_s = \frac{4f_p}{2N+1}, N > 0$$

(5)

Here $N$ is the subsampling ratio.

The excess loop delay in the proposed modulator is designed by $e^{-\alpha s}$, where $\alpha$ designed the total delay in the feedback path of the modulator. A sine shaped pulse is assumed for the DAC in order to reduce the jitter effects on the modulator. A linear model of a fourth order CT-subsampling $\Sigma\Delta$ modulator is presented in Fig. 7[9]. Where, $R_1$ and $R_2$ designed two identical second order continuous time BAW resonators with the same transfer function $H(s)$. As detailed in [9], the open loop transfer function of the modulator in the $z$-domain can be written as:

$$GH(z) = Z\left[L^{-1}\left((k_1H(s)^2 + k_2H(s))H_{dac}(s)e^{-\alpha s}\right)\right]$$

(6)

where $H_{dac}$ is the impulse response at the output of the sine shaped DAC. It is expressed as[9]:

$$H_{dac}(s) = \frac{w_{dac}^2(1-e^{-sT_e})}{s(s^2 + w_{dac}^2)}$$

(7)

Here, $w_{dac} = 2\pi f_{dac}$. Where $f_{dac}$ is the input frequency of the sine shaped signal at the DAC[9]. The Signal and Noise Transfer Function respectively $STF(z)$ and $NTF(z)$ are given by:

$$STF(z) = \frac{Z\left[L^{-1}\left(H(s)^2\right)\right]}{1+GH(z)}$$

(8)

$$NTF(z) = \frac{1}{1+GH(z)}$$

(9)

B. Simulation Results and Performances Analysis

Assuming that each BAW resonator based $\Sigma\Delta$ Modulator in Fig. 7 have a resonant frequency $f_p = 1.58$ GHz and an anti-resonant frequency $F_s = 1.42$ GHz with a undersampling ratio $N = 3$. Then, the sampling frequency, $F_s$ is around 902.85 MHz and the excess loop delay, $t_e = 1.5 = F_s$, and $f_{dac}$ 1.8 GHz. In order to preserve the stability of the modulator, the coefficients of loop filter are choosing as $k_1 = k_2 = 0.7$. The NTF and the STF frequency response deduced from equation (8) and (9) of the proposed modulator with and without anti-resonance cancellation technique are given in Fig. 8. We can see the anti-resonance effects in the STF frequency response. In fact, without the anti-resonance cancelation, an unwanted peak appears to the intermediate frequency, $f_{A4} = 225.71$ MHz and STF magnitude at the output of the modulator is minimal around this frequency. Although, using a BAW with anti-resonance technique, the signal input is filtered without undesirable frequency components. While, the NTF frequency response is identical with and without anti-resonance cancellation. This problem can lead to negative effects on the SNR at the output of the modulator. In Fig. 9.

![Fig. 7. A linear model of the proposed $\Sigma\Delta$ modulator](image)

![Fig. 8. STF and NTF transfer function of the proposed modulator with BAW resonator](image)

![Fig. 9. SNR versus input amplitude of a CT-subsampling $\Sigma\Delta$ Modulator with and without compensated BAW resonator](image)

We have plotted the SNR at the output of the proposed BAW modulator with and without anti-resonance system. We can see that the maximum attainable SNR with non-compensated BAW resonator (with anti-resonance) is 52 dB. While, if we use an anti-resonance cancellation system, the maximum value of SNR is reduced to 38dB. We can conclude that the using of BAW resonator based subsampling CT-$\Sigma\Delta$ modulator, the SNR will be deteriorated at the output of the modulator. However, we can resolve this problem with anti-resonance system.

IV. Conclusion

In this paper, a new design technique to optimize the CT-subsampling bandpass $\Sigma\Delta$ modulator is presented. The CT-loop filter of the modulator is based on BAW resonator. Antiresonance is the major issue in the kind of the resonator. A design method to cancel this problem is
discussed. A design example for a CT-subsampling bandpass fourth order $\Sigma\Delta$ modulator based BAW resonator is simulated.

REFERENCES


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